

Table 1: Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
V_{DRM}/V_{RRM}	600	V
$I_{GT} (min./max.)$	1.5 / 5	mA

DESCRIPTION

The TYN612M SCR is suitable to fit modes of control found in applications such as voltage regulation circuits for motorbikes, overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits, capacitive discharge ignition.

The insulated fullpack package allows a back to back configuration.

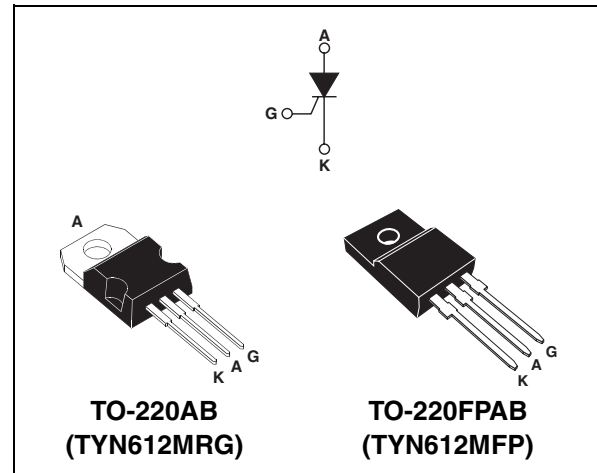


Table 2: Order Codes

Part Number	Marking
TYN612MRG	TYN612M
TYN612MFP	TYN612MFP

Table 3: Absolute Ratings (limiting values)

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)	TO-220AB $T_c = 105^\circ\text{C}$	12
		TO-220FPAB $T_c = 70^\circ\text{C}$	
$I_{T(AV)}$	Average on-state current (180° conduction angle)	TO-220AB $T_c = 105^\circ\text{C}$	8
		TO-220FPAB $T_c = 70^\circ\text{C}$	
I_{TSM}	Non repetitive surge peak on-state current	$t_p = 8.3 \text{ ms}$ $T_j = 25^\circ\text{C}$	125
		$t_p = 10 \text{ ms}$ $T_j = 25^\circ\text{C}$	
I^2t	I^2t Value for fusing	$t_p = 10 \text{ ms}$ $T_j = 25^\circ\text{C}$	72
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100 \text{ ns}$	$F = 60 \text{ Hz}$ $T_j = 125^\circ\text{C}$	50
I_{GM}	Peak gate current	$t_p = 20 \mu\text{s}$ $T_j = 125^\circ\text{C}$	4
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^\circ\text{C}$	1
T_{stg}	Storage junction temperature range	- 40 to + 150	$^\circ\text{C}$
T_j	Operating junction temperature range	- 40 to + 125	
V_{RGM}	Maximum peak reverse gate voltage	5	V

Tables 4: Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Test Conditions		Value	Unit
I_{GT}	$V_D = 12\text{ V}$ $R_L = 140\ \Omega$	MIN.	1.5	mA
		MAX.	5	
V_{GT}		MAX.	1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3\text{ k}\Omega$	$T_j = 125^\circ\text{C}$ MIN.	0.2	V
I_H	$I_T = 500\text{ mA}$ Gate open	MAX.	20	mA
I_L	$I_G = 1.2\ I_{GT}$	MAX.	40	mA
dV/dt	$V_D = 67\ \% \ V_{DRM}$ Gate open	$T_j = 125^\circ\text{C}$ MIN.	50	V/ μs
V_{TM}	$I_{TM} = 24\text{ A}$ $t_p = 380\ \mu\text{s}$	$T_j = 25^\circ\text{C}$ MAX.	1.6	V
V_{t0}	Threshold voltage	$T_j = 125^\circ\text{C}$ MAX.	0.85	V
R_d	Dynamic resistance	$T_j = 125^\circ\text{C}$ MAX.	30	$\text{m}\Omega$
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$ MAX.	5	μA
		$T_j = 125^\circ\text{C}$	2	mA

Table 5: Thermal Resistances

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	TO-220AB	1.3	$^\circ\text{C/W}$
		TO-220FPAB	4.5	
$R_{th(j-a)}$	Junction to ambient	TO-220AB	55	$^\circ\text{C/W}$
		TO-220FPAB	55	

Table 6: Product Selector

Part Number	Voltage	Sensitivity	Package
TYN612MRG	600V	5mA	TO-220AB
TYN612MFP	600V	5mA	TO-220FPAB

Figure 1: Maximum average power dissipation versus average on-state current

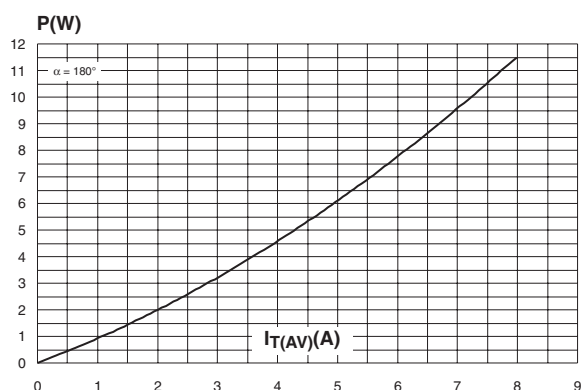


Figure 2: Average and D.C. on-state current versus case temperature (TO-220AB)

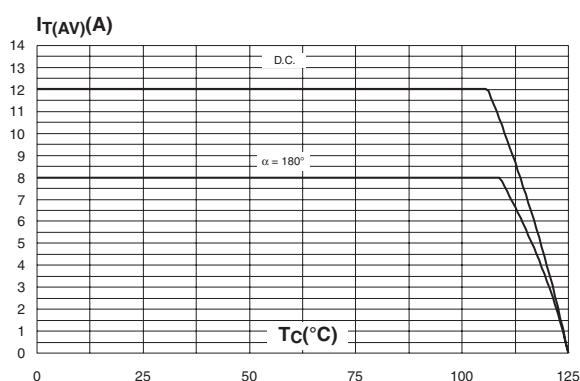


Figure 3: Average and D.C. on-state current versus case temperature (TO-220FPAB)

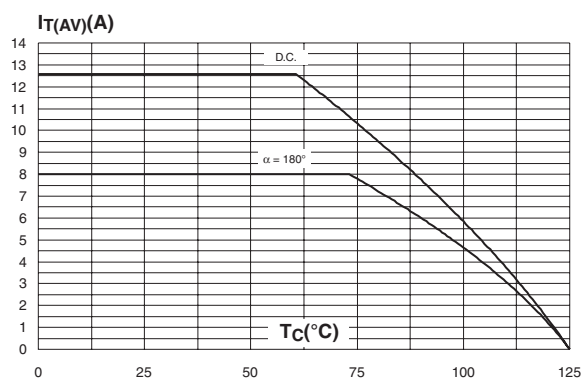


Figure 4: Relative variation of thermal impedance versus pulse duration (TO-220AB)

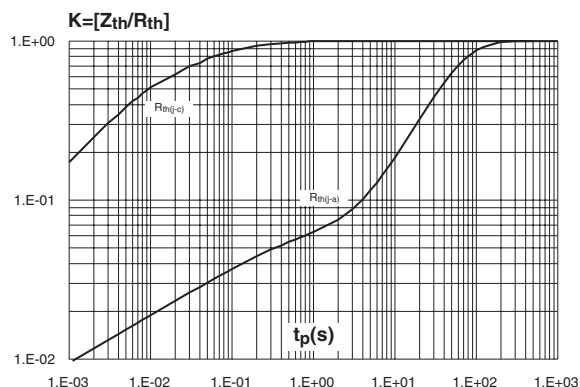


Figure 5: Relative variation of thermal impedance versus pulse duration (TO-220FPAB)

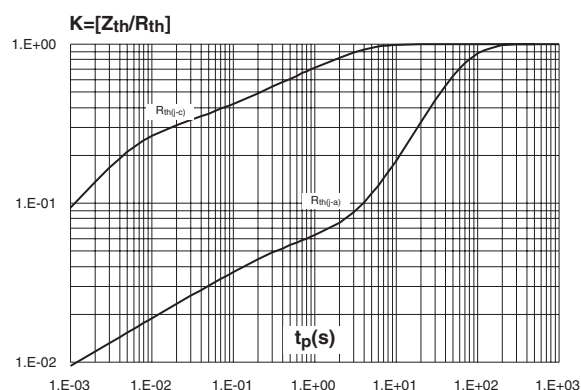


Figure 6: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

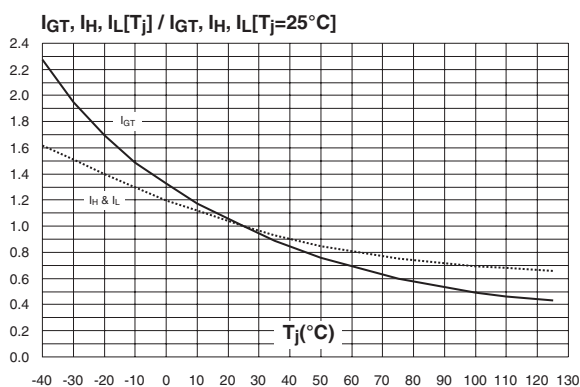


Figure 7: Surge peak on-state current versus number of cycles

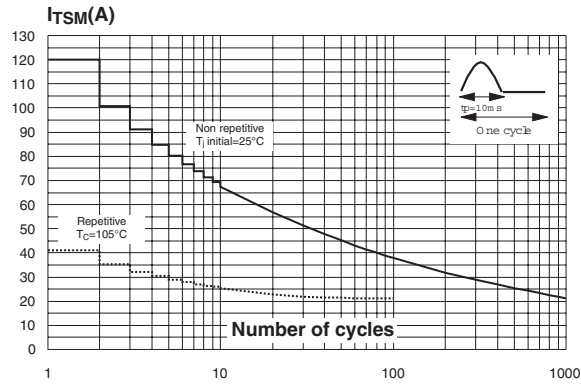


Figure 8: Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t

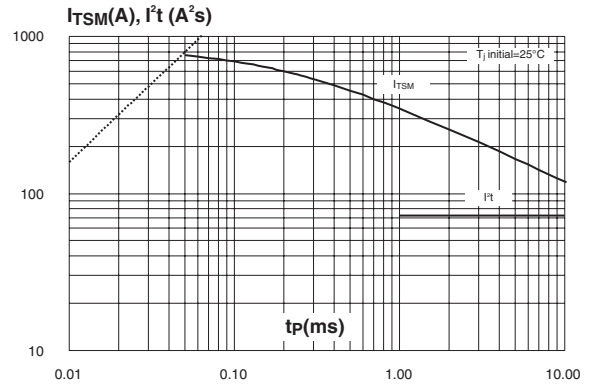


Figure 9: On-state characteristics (maximum values)

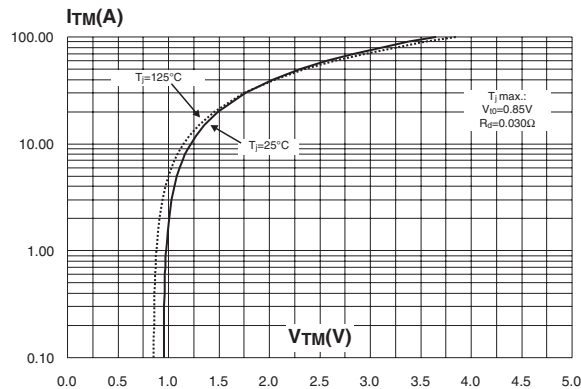


Figure 10: Ordering Information Scheme

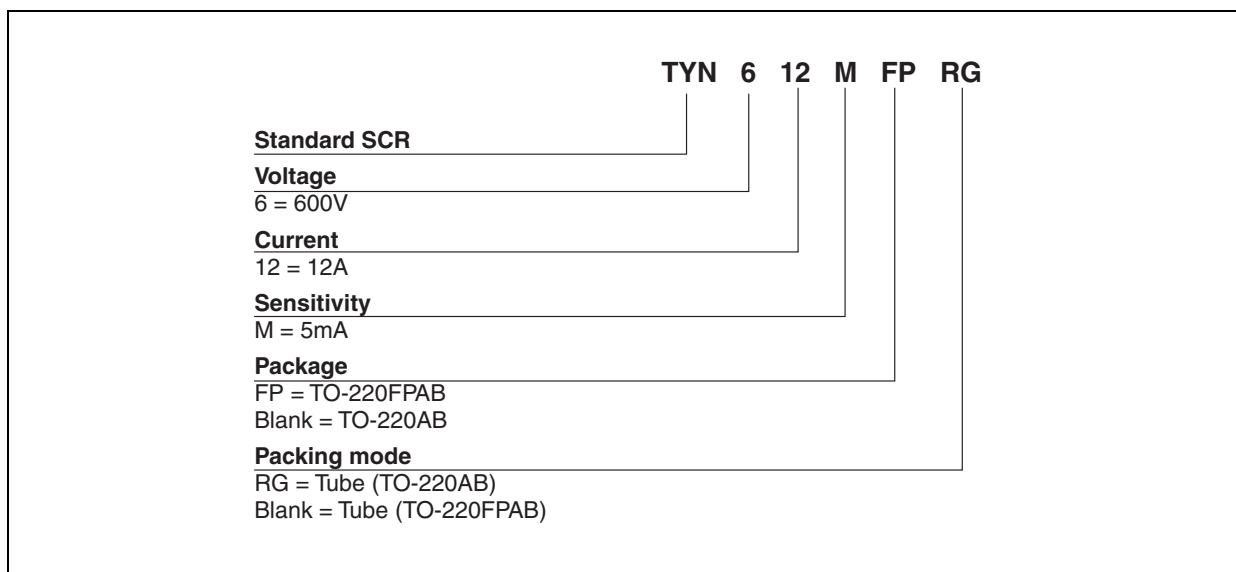


Figure 11: TO-220AB Package Mechanical Data

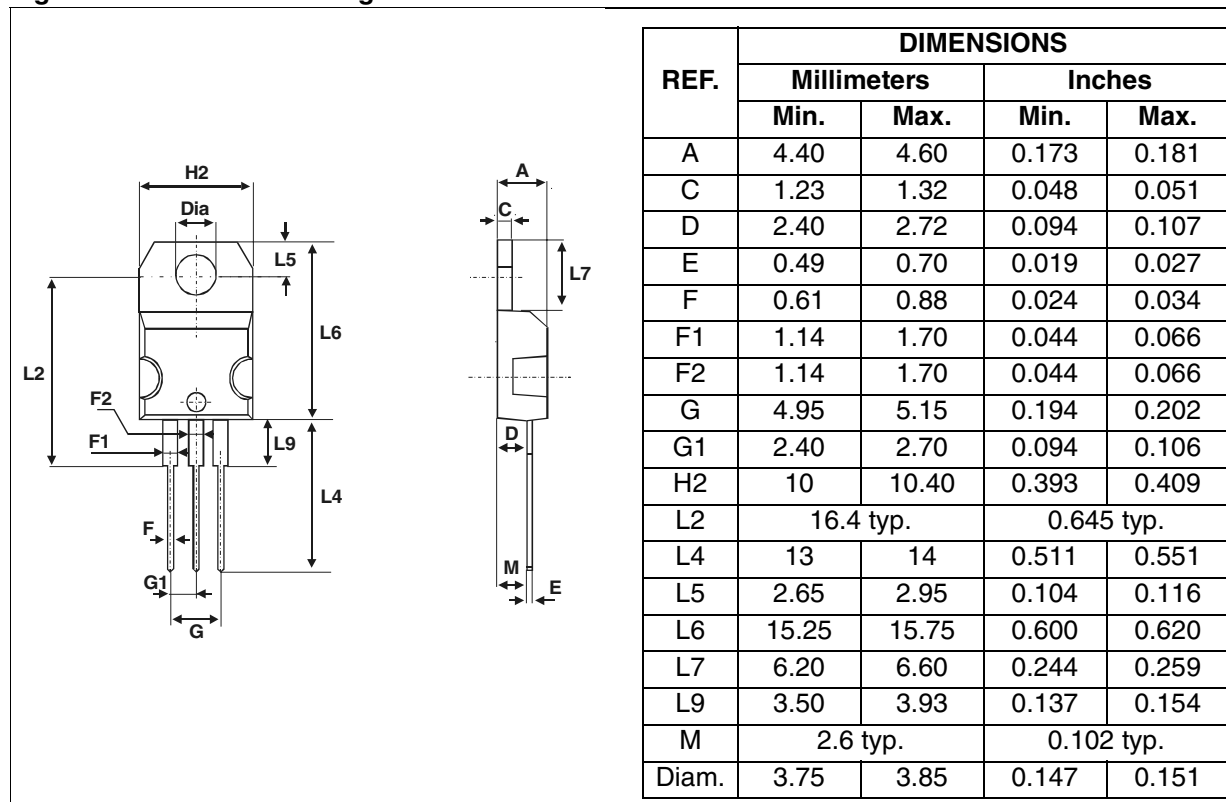
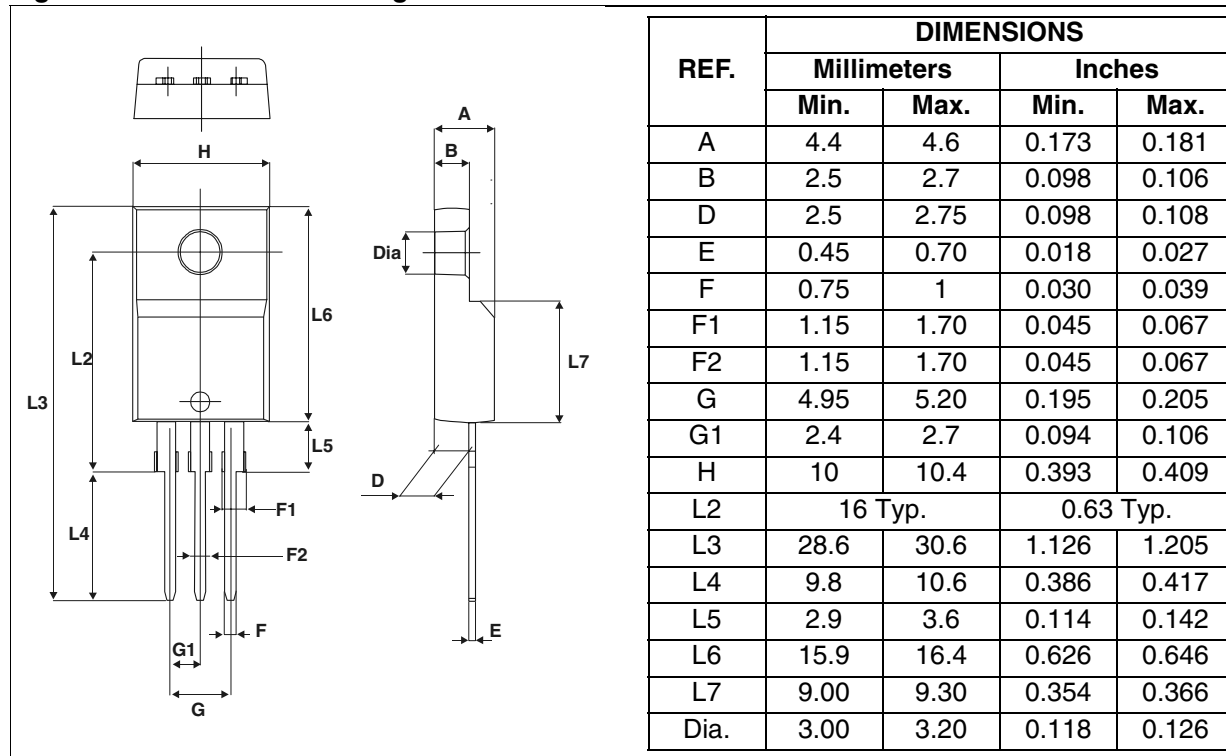


Figure 12: TO-220FPAB Package Mechanical Data



TYN612M

Table 7: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
TYN612MRG	TYN612M	TO-220AB	2.3 g	50	Tube
TYN612MFP	TYN612MFP	TO-220FPAB	2 g	50	Tube

Table 8: Revision History

Date	Revision	Description of Changes
Sep-2002	1A	Last update.
10-Fev-2005	2	TO-220FPAB package added.

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